

3.0 Volt-only Page Mode Flash Memory featuring 90 nm MirrorBit Process Technology, Flash 256MB 3.0-3.6V 90NS -40-85C PBF

Manufacturers	Infineon Technologies Corporation
Package/Case	TSOP-56
Product Type	Memory
RoHS	Rohs
Lifecycle	



Images are for reference only

Please submit RFQ for S29GL256P90TFIR10 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

The S29GL256P90TFIR10 is a specific model of parallel NOR Flash memory IC from Cypress Semiconductor.

Features

- Memory Capacity: 256 Megabits (32 Megabytes)
- Parallel Interface: 16-bit
- Operating Voltage: 2.7V to 3.6V
- Read Speed: 90 ns
- Page Size: 512 words (each word is 16 bits)
- Sector Erase Size: 128 kilobytes or 256 kilobytes
- Operating Temperature Range: -40°C to +85°C
- Package: 48-pin TSOP (Thin Small Outline Package)
- RoHS Compliance: Yes

Application

- Data storage in various electronic devices
- Firmware storage in embedded systems
- Industrial automation and control systems
- Automotive applications
- Consumer electronics

Related Products



[S29GL064S70TFI040](#)

Infineon Technologies Corporation
Tube



[S29GL128S90TFI010](#)

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[S29GL512S11TFI020](#)

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56-TFSOP (0.724", 18.40mm Width)



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